

EE 735: ASSIGNMENT 2 REPORT

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ROLL NO.: 16D070010

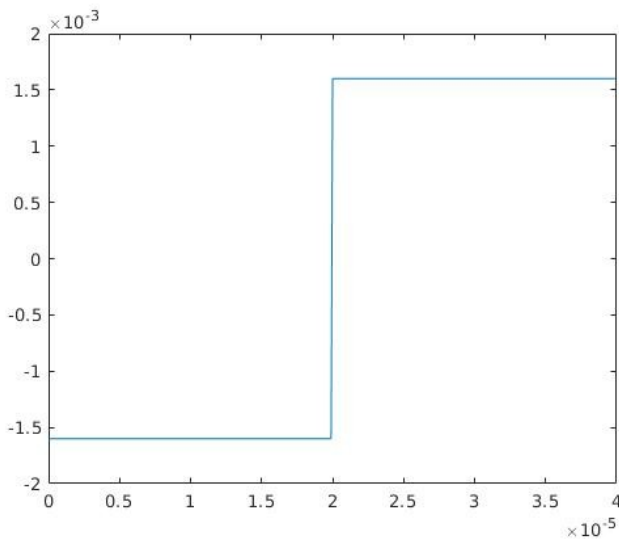
Q1. I keep length of ntype = length of ptype = 200nm
p-type is from 0-200 nm and 200-400 nm is ntype in the xgrid.

$N_D = 10^{16} \text{ cm}^{-3}$, $N_A = 10^{16} \text{ cm}^{-3}$

For the abrupt junction,

in 0-200(x_p) nm, we say that $\rho_{oh} = -q \cdot N_A$ and 200-400($x_p + x_N$)nm, we say that $\rho_{oh} = q \cdot N_D$

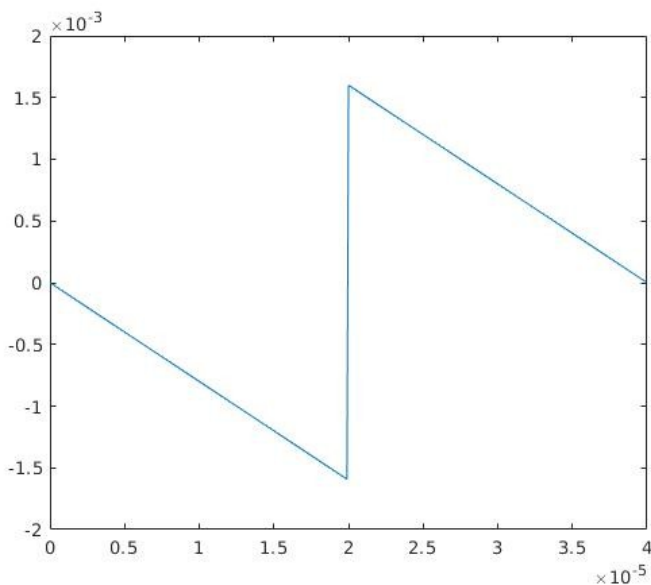
For the abrupt graded junction, ρ_{oh} is as follows:



For the linearly junction,

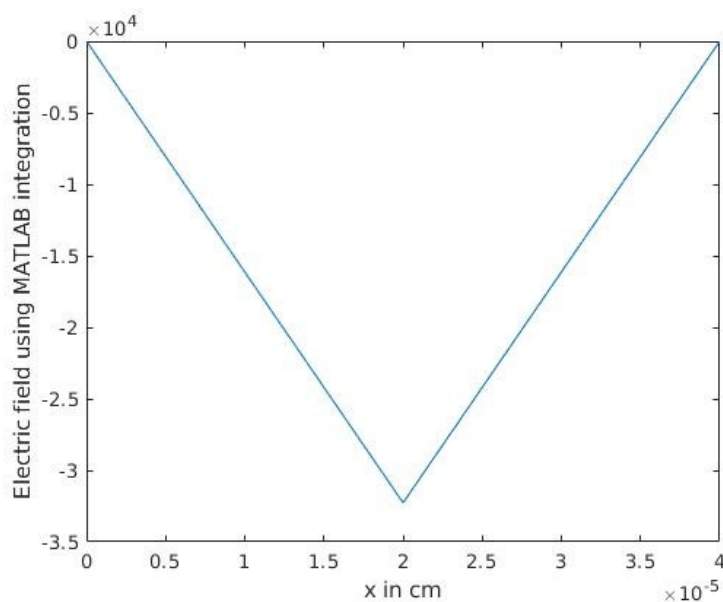
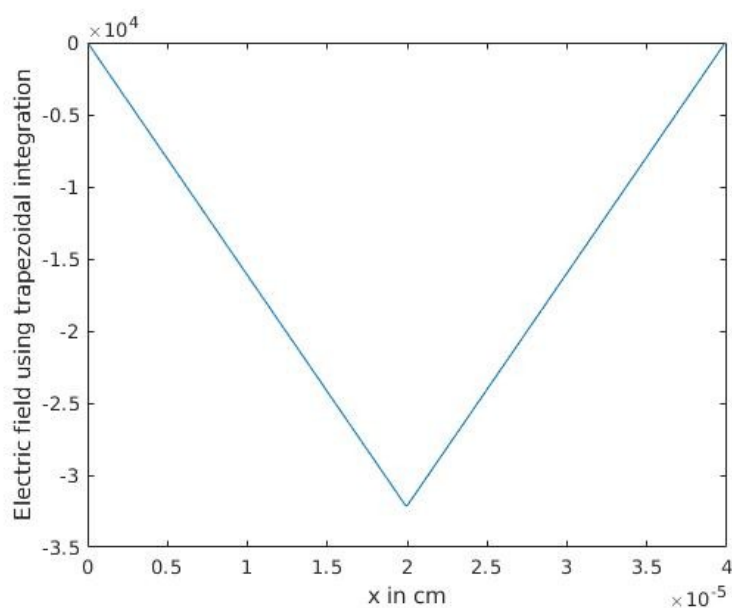
in 0-200(x_p) nm, we say that $\rho_{oh} = -(q \cdot N_A / x_p) \cdot x$; and 200-400($x_p + x_N$)nm, we say that $\rho_{oh} = -(q \cdot N_D / x_N) \cdot (x_N + x_p - x)$;

For the linearly graded junction, ρ_{oh} is as follows:

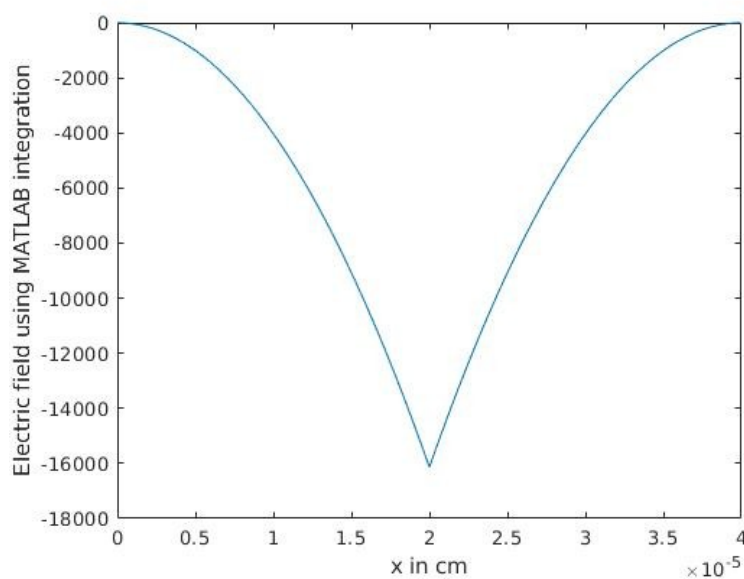
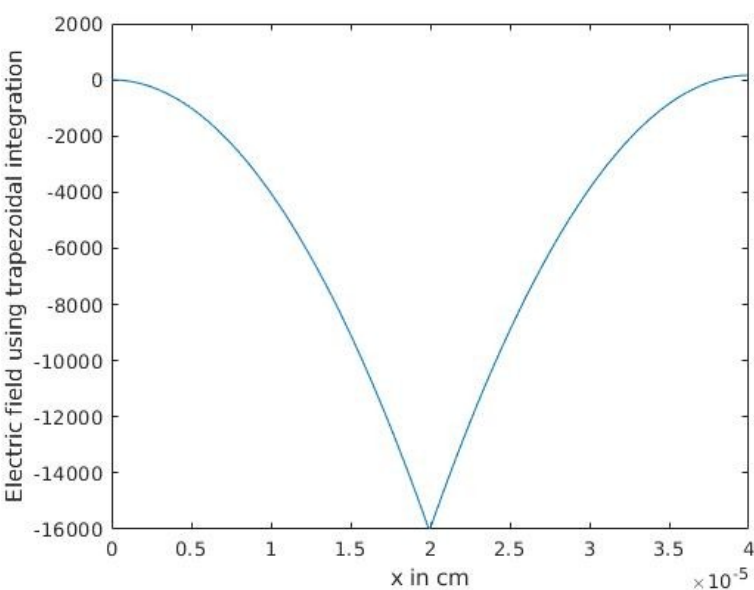


Q1 a) Electric field profile by solving the Gauss Law using numerical integration techniques such as Trapezoidal method

i) Abrupt junction



ii) Linearly graded junction

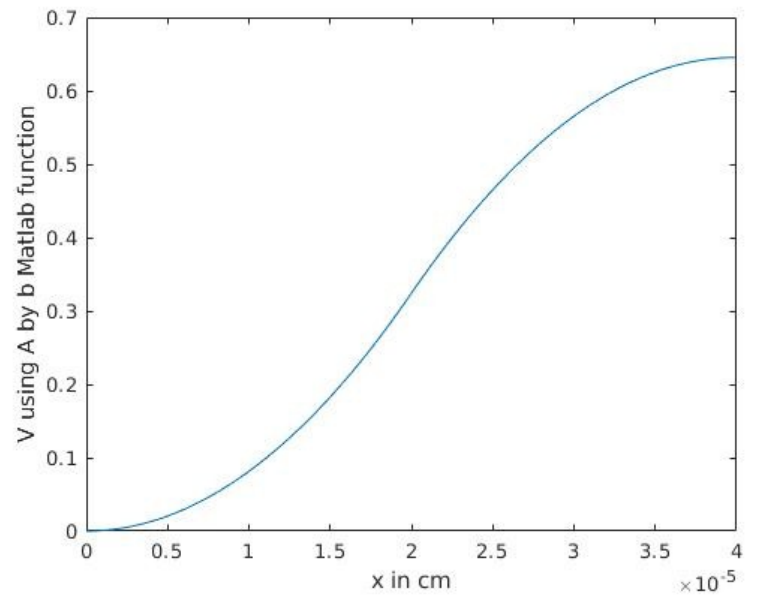
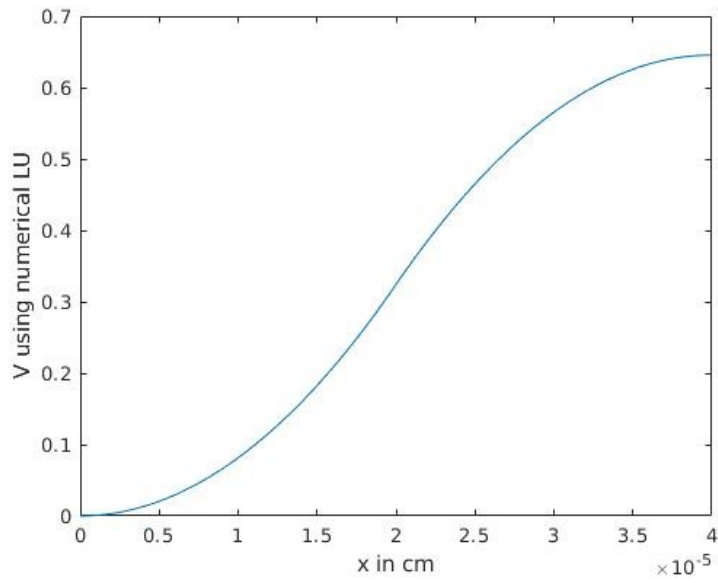


In case (i), numerical and MATLAB integration work similarly.

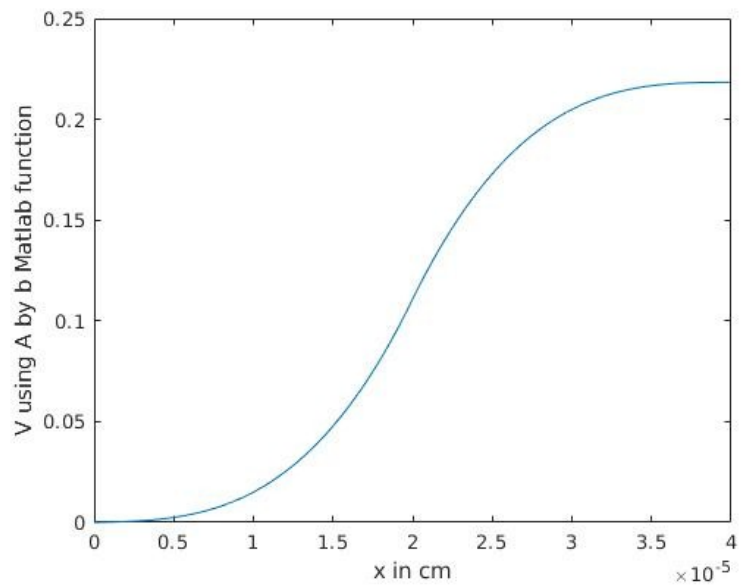
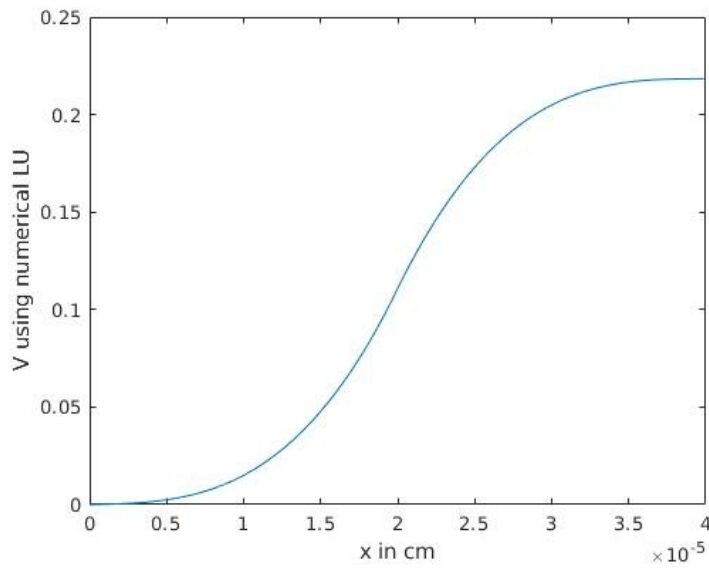
A slight difference can be seen in case (ii) where electric field doesn't come out to be exactly zero at $x=400\text{nm}$ boundary using the numerical integration technique.

Q1 b) Using central difference discretization scheme, solved the Poisson equation with depletion approximation.

i) Abrupt junction



ii) Linearly graded junction



LU decomposition matrices obtained were nearly equal from numerical and MATLAB methods

Q2. Doping concentrations $N_D = 10^{16} \text{ cm}^{-3}$, $N_A = 2 \times 10^{15} \text{ cm}^{-3}$. Used Newton Raphson method to solve the charge neutrality equation for finding the fermi energy E_F .

Taking $E_V = 0$; $E_D = E_C - 0.045 \text{ eV}$; $E_A = E_V + 0.045 \text{ eV}$ at 300K and solving the equation, we obtain $E_F = 0.8895 \text{ eV}$